# PRODUCTION OF AMMONIA IN A PACKED-BED DIELECTRIC BARRIER DISCHARGE

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# ABSTRACT

We investigate the production of ammonia from nitrogen and hydrogen in a dielectric barrier discharge packed with glass spheres and magnesium oxide pellets close to atmospheric pressure. In particular, the influence of the discharge power and the gas composition is studied. The maximum ammonia production yields obtained is 4.9% conversion efficiency of  $H_2$  to  $NH_3$  and the maximum energy efficiency is 0.47 g/kWh. Ammonia synthesis from gas phase reactions only (without a catalyst) was also tested. We find that catalytic surface reactions dominate. allowing relatively high concentrations of ammonia to be produced despite the low electron energies present in a low-temperature non-equilibrium plasma.

# **1. INTRODUCTION**

The standard Haber–Bosch process for ammonia production requires high pressures and temperatures (typically 200 bar and 500°C), as well as a catalyst, for acceptable production rates and yields, usually around a 15% conversion of hydrogen to ammonia. By combining an atmospheric-pressure plasma with a catalyst, it is, however, possible to produce ammonia from nitrogen and hydrogen at atmospheric pressure and room temperature [1].

In order to increase ammonia production, a wide range of catalysts and different plasma-catalyst configurations has been tested [2-5]. The catalyst can be in the form of a surface, a wire or beads; Pd, Pt, Fe, MgO, and  $Al_2O_3$  have been most frequently-used catalytic materials. The catalyst can be placed within or downstream from the discharge. Ruan et al. [6] reported the highest ammonia concentration, 12% by volume, using a dielectric-barrier discharge packed with beads of MgO supporting Cs-Ru, with the residence time of 120 min.

We use a dielectric-barrier-discharge reactor, similar to that of Ruan et al., packed with glass and MgO beads with the residence time of 23 to 102 s. We investigate the influence of the input gas composition (including the addition of argon to the nitrogen-hydrogen mixture) and applied voltage on the production of ammonia. We use measurements electrical and emission spectroscopy to obtain the power, the electron density, the electron energy distribution function (EEDF) and rotational and vibrational temperatures, and use these data to understand the influence of applied voltage and gas composition. For comparison, we also present results obtained for the reactor without any glass or MgO beads present.

# **2. EXPERIMENT**

A cylindrical dielectric-barrier discharge reactor was used in this work and the reactor has a stainless-steel central high-voltage electrode, a 4mm-thick borosilicate glass tube as a dielectric barrier and a 200-mm-long and 56-mm-diameter bronze-mesh cylinder as the outer ground electrode. The 5-mm gap between the highvoltage electrode and the dielectric barrier was filled with soda-lime glass spheres (3 mm diameter) and MgO pellets (approximately 2 mm long and 1 mm diameter). For comparison, the reactor was also operated without glass spheres and MgO pellets.

A Trek 20/20C high-voltage amplifier, fed by a 1 kHz sine wave, was used as the power source. The ammonia concentration in the exit gas was

measured using a mass spectrometer (Stanford Research Systems SRS-300) or a Fouriertransform infrared (FT-IR) spectrometer (Perkin-Elmer Frontier), calibrated against measurements made using a Thermo Fisher Scientific Orion ammonia ion-selective electrode.

Measured I-V characteristics were used to determine the absorbed power, estimate the electron density, and to obtain, using BOLSIG+ [7], the electron energy distribution function (EEDF). Emission spectra were obtained using a SP2500 Princeton Instruments Acton spectrometer. The rotational and vibrational population temperatures and the relative densities of the different vibrational excited states were estimated from the measured  $N_2^+$ spectra between 385 and 395 nm using the LIFBASE 2.1 software [8].

# **3. RESULTS AND DISCUSSION**

#### 3.1 Influence of applied voltage and argon

The influence of applied voltage and the addition of argon on the NH<sub>3</sub> production yield (conversion of  $H_2$  to  $NH_3$ ) is investigated using The pressure The FT-IR. was 1 atm. measurement results are shown in Fig. 1. The yield increases from 1.6 to 4.9%, corresponding  $NH_3$ production rate of 12.8 to and 37.6 µmol/min respectively, when the voltage is increased and argon added. At the same time, the absorbed power increases from 35 to 90 W and the rotational temperature from  $300 \pm 50$  K to  $450 \pm 50$  K.

The EEDF for different conditions is shown in Fig. 2. Since the dissociation energy of  $N_2$  is 9.8 eV, the likelihood of direct dissociation by electron impact is low, particularly for the lower applied voltage. Increasing the applied voltage increases the reduced electric field strength E/N, where E is the electric field strength across the gas gap and N denotes the gas number density, and shifts the EEDF to higher energies. The addition of Ar slightly reduces the calculated E/N, and resulted in a small decrease in the number of high energy electrons. The molecular  $N_2$  and  $N_2^+$ emission intensities are observed to be enhanced by the addition of Ar, as well as by the increased voltage, as shown in Fig. 3. Increased vibrational excitation of N<sub>2</sub> may increase the likelihood of dissociative adsorption on the catalyst surface,

which is claimed to be the main method of  $N_2$  dissociation [1]. The addition of Ar may also increase gas-phase dissociation. The electron density is increased  $15 \pm 3\%$  with Ar addition at the same voltage , suggesting that a significant density of Ar<sup>+</sup> ions is produced The charge transfer reaction with Ar<sup>+</sup> will lead to increased dissociation of  $N_2$  [9] and supports the higher emission intensity of  $N_2^+$  and enhanced NH<sub>3</sub> production yield.



Fig. 1 NH<sub>3</sub> production yield and power consumption for different applied voltages and different argon flows. The N<sub>2</sub> flow is 30 sccm and the H<sub>2</sub> flow is 30 sccm. The voltage is 11 kV for the 3 cases on the left, and 13 kV for the 2 cases on the right.



Fig. 2 Influence of applied voltage and argon addition on EEDF. The  $N_2$ ,  $H_2$  and Ar flows are respectively 30, 30 and 10 sccm.



Fig.3 N<sub>2</sub> 2nd positive system N<sub>2</sub>( $C^3\Pi_{\mu}$ )  $\rightarrow$  N<sub>2</sub> ( $B^3\Pi_8$ ) and N<sub>2</sub><sup>+</sup> emission intensities, for the same conditions used for Fig. 2

# 3.2 Influence of $H_2$ input flow

To understand the influence of  $H_2$  on  $NH_3$ generation, we performed a series of measurements for different  $H_2$  input flow rates. In these experiments,  $NH_3$  production was measured with the mass spectrometer. Unlike the experiments reported in Sec. 3.1, the pressure at the gas outlet of the reactor was sub-atmospheric,  $310 \pm 50$  torr. Although the pressure in the reactor is expected to be higher, the pressure at the gas exit was used in calculation of the production yield to give a conservative estimate.

As shown in Fig. 4, the  $NH_3$  production rate increases monotonically with  $H_2$  input flow rate, but the conversion efficiency of  $H_2$  to  $NH_3$  is largest at the lowest  $H_2$  flow rate of 10 sccm.



Fig.4. Dependence on  $H_2$  input flow rate of the NH<sub>3</sub> production yield and production rate. The  $N_2$  input flow rate is 30 sccm, and the applied voltage is 12 kV.



Fig.5. EEDF for different H<sub>2</sub> input flow rates

Addition of  $H_2$  shifts the EEDF to lower electron energies, as shown in Fig. 5, except for a small increase for 10 sccm  $H_2$ . Note that the EEDFs were calculated for a pressure of 1 atm; using a lower pressure shifts the EEDFs to higher energies, but the trends observed for increasing  $H_2$  flows are the same. The vibrational temperature decreases from 2200 K to 1250 K, and the electron temperature from 15 900 K to 12 300 K, as the  $H_2$  flow rate increases, as shown in Fig. 6. As a result, the relative population density of the first excited vibrational energy state of  $N_2^+(B)$  relative to the ground state,  $n[N_2^+(B,v=1)] / n[N_2^+(B,v=0)]$ , is reduced from 0.212 to 0.065. The light emission intensity from the N<sub>2</sub> 2nd positive system is observed to be significantly weakened, even for 10 sccm  $H_2$  input flow. This means the population densities of the electronically-excited states  $N_2(C^3\Pi_u)$  and  $N_2(B^3\Pi_g)$  are expected to be decreased as well as the vibrationally-excited states of  $N_2^+(B)$ . There is, however, a remarkable increase in the electron number density, also shown in Fig. 6. Since the addition of H<sub>2</sub> decreases the electron energy distribution function at higher energies, and reduces the population densities of the excited states of  $N_2$ and  $N_2^+$ , the increased electron density is likely to be due to the ionization of hydrogen. The results indicate that high-energy electrons are being lost due their interactions with H<sub>2</sub>, leading to vibrational excitation and ionization. The increased production rate, and approximately constant yield, which occur in spite of decreased vibrational excitation of N<sub>2</sub>, suggests that vibrationally-excited and ionized H<sub>2</sub> molecules play an important role in NH<sub>3</sub> production.



Fig.6. Dependence of electron and vibrational temperatures and electron density on  $H_2$  input flow rate. Other parameters are as for Fig. 4.

#### 3.3 Comparison with gas-phase reaction

In order to investigate the importance of the surface reactions, the reactor was run without MgO beads and glass spheres. Because of the large 5 mm gap, 50 sccm of Ar was added to assist breakdown. The pressure in the reactor was  $120 \pm 20$  torr. The coupled power and the energy

efficiency of  $NH_3$  production are compared to the packed-bed reactor case in Fig. 7.

Removing the MgO and glass spheres increased both the coupled power and the gas temperature; despite this the production yield is decreased by a factor of 4.4 for an  $H_2$  input flow rate of 50 sccm. The energy efficiency is decreased by a factor of 5.6 times at the same flow rate.

The results suggest that surface reactions play an important role in the production of  $NH_3$ . It is likely that surface reactions on the stainless-steel inner electrode and the glass tube contribute to the production of  $NH_3$ , so the contribution of gas-phase reactions is probably even smaller than the approximately 20% immediately suggested by the results.



Fig.7. Comparison of energy efficiency of NH<sub>3</sub> production and coupled power for the reactor with and without MgO beads and glass spheres. The N<sub>2</sub> and Ar flow rates were 30 sccm and 50 sccm respectively, and the applied voltage was 12 kV.

# **4. CONCLUSIONS**

The heterogeneous production of  $NH_3$  from  $N_2$ and  $H_2$  has been investigated with a packed-bed dielectric-barrier discharge reactor. Appreciable yields of  $NH_3$  have been obtained, especially with addition of Ar. Experiments performed without the presence of catalyst suggest that gasphase reactions are responsible for only a small portion of the  $NH_3$  synthesis.

We have derived EEDFs, electron densities and electron and vibrational temperatures, in an effort to understand the important reactions that lead to the production of  $NH_3$ . It is clear that the presence of Ar and  $H_2$  ions leads to increased  $NH_3$  production, possibly through charge-transfer reactions.

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